राष्ट्रीय प्रौद्योगिकी संस्थान मिजोरम NATIONAL INSTITUTE OF TECHNOLOGY MIZORAM

(An Institute of National Importance under Ministry of Education, Govt. of India) CHALTLANG, AIZAWL, MIZORAM – 796012



Course Structure & Syllabus for Minor in VLSI and Semiconductor Technology

for existing BTech in ECE and BTech in CSE <u>ACADEMIC SESSION: 2023-24 onwards</u>

सूक्ष्म कणिका एवं संचार अभियांत्रिकी विभाग Center of Interdisciplinary Research (CIR)

Course Structure & Syllabus for Minor in VLSI and Semiconductor Technology Classification of Credits Points:

1 Hr Lecture (L) per week	1.0 Credit	1 Hr Tutorial (T) per week	1.0 Credit
1 Hr Laboratory (P) per week	0.5 Credit	AUDIT Course	NO Credit

Course Code	Course Name	Category	L-T-P	Credit
CIRL 1X01	Compound Semiconductors	DC	3-0-0	3
CIRL 1X02	VLSI Technology	DC	3-0-0	3
CIRL 1X03	Nanoelectronic Semiconductor Devices	DC	3-0-0	3
CIRL 1X04	Analog VLSI Circuits	DC	3-0-0	3
CIRL 1XXX	Program Elective – I	DE	3-0-0	3
CIRL 1XXX	Program Elective – II	DE	3-0-0	3
CIRL 1XXX	Program Elective – III	DE	3-0-0	3
CIRL 1XXX	Program Elective – IV	DE	3-0-0	3
CIRP 1X01/	Analog VLSI Laboratory /	DC	0-0-2	1
CIPR 1X02	VLSI Design Laboratory	DC	0-0-2	I
CIRP 1X03	VLSI Device Modelling Laboratory	DC	0-0-2	1
		TOTAL	24-0-4	26

PROGRAM ELECTIVES

S1. No.	Course Code	Course Name			
1	CIRL 1X05	Foundation of VLSI			
2	CIRL 1X06	Semiconductor Device Modelling			
3	CIRL 1X07	Foundations of MEMS			
4	4 CIRL 1X08 Low power VLSI Design				
5	CIRL 1X09	VHDL Modelling			
6	CIRL 1X10	Physics of Nanoscale FET			
7	CIRL 1X11	Semiconductor Materials and Systems			
8	CIRL 1X12	Semiconductor Optoelectronics: Theory and Design			
9	CIRL 1X13	Digital VLSI Circuits			

CORE COURSES

CIRL 1X05 Compound Semiconductors								
L-T-P: 3-0-0								Credits: 3
As per the Engineering			by	Dept.	of	Electronics	and	Communication

CIRL 1X02 VLSI Technology									
L-T-P: 3-0	0-0								Credits: 3
As per Engineeri				by	Dept.	of	Electronics	and	Communication

CIRL 1X03 Nanoelectronic Semiconductor Devices										
L-T	-P: 3	-0-0								Credits: 3
			syllabus of ECL 1X0		by	Dept.	of	Electronics	and	Communication

CIRL 1X04 Analog VLSI Circuits							
L-T-P: 3-0-		Credits: 3					
-	e syllabus prescribed by Dept. of Electronics and of ECL 2102.	Communication					

CIRP 1X01	Analog VLSI Laboratory	
L-T-P: 0-0-2		Credits: 1
As per the syllabus o	f ECP 2101.	

CIRP 1X02	VLSI Design Laboratory	
L-T-P: 0-0-2		Credits: 1
As per the syllabus	of ECP 1603.	

CIRP 1X03	VLSI Device Modelling Laboratory	
L-T-P: 0-0-3		Credits: 1
As per the syllabus of ECP	2202.	

Program Elective(s)

CIRL 1X01 Foundation of VLSI							
L-T-P: 3-0-0		Credits: 3					
As per the Engineering of	syllabus prescribed by Dept. of Electronics and of ECL 1503.	Communication					

CIRL 1X06 Semiconductor Device Modelling									
L-T-P: 3	-0-0								Credits: 3
		syllabus of ECL 210		by	Dept.	of	Electronics	and	Communication

CIRL 1X	CIRL 1X07 Foundations of MEMS											
L-T-P: 3-0	0-0								Credits: 3			
As per t Engineerir				by	Dept.	of	Electronics	and	Communication			

CIR	CIRL 1X08 Low power VLSI Design											
L-T-	-P: 3	-0-0								Credits: 3		
			syllabus of ECL 1X(by	Dept.	of	Electronics	and	Communication		

CIRL 1X09 VHDL Modelling										
L-T-I	P: 3 -	0-0								Credits: 3
			syllabus of ECL 1X1		by	Dept.	of	Electronics	and	Communication

CIRL 1X10 Physics of Nanoscale FET										
L-T-	-P: 3	-0-0								Credits: 3
	-		syllabus of ECL 1X1	-	by	Dept.	of	Electronics	and	Communication

CII	CIRL 1X11 Semiconductor Materials and Systems											
L-T	`-P: 3	-0-0								Credits: 3		
			syllabus of ECL 1X2		by	Dept.	of	Electronics	and	Communication		

CIRL 1X1	CIRL 1X12 Semiconductor Optoelectronics: Theory and Design											
L-T-P: 3-0-	D							Credits: 3				
As per th Engineering			by	Dept.	of	Electronics	and	Communication				

CIRL 1X13 Digital VLSI Circuits											
L-T-P: 3-0-0							Credits: 3				
+	syllabus prese of ECL 2103.	cribed by	Dept.	of	Electronics	and	Communication				